Vishay General Semiconductor

Surface Mount PAR[®] Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



- Junction passivation optimized design passivated anisotropic rectifier technology
- T_J = 175 °C capability suitable for high reliability and automotive requirement

RoHS COMPLIANT

- · Available in uni-directional polarity only Low leakage current
- Low forward voltage drop
- High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- · Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AB

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("X" denotes revision code e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	VALUE	UNIT				
Peak pulse power dissipation	with 10/1000 µs waveform	D	3600	W			
	with 10/10 000 µs waveform	P _{PPM}	2800				
Power dissipation on infinite heats	PD	5.0	W				
Peak pulse current with 10/1000 µ	I _{PPM} ⁽¹⁾	See next table	А				
Peak forward surge current 8.3 m	I _{FSM}	500	А				
Operating junction and storage te	T _J , T _{STG}	-55 to +175	°C				

Note

⁽¹⁾ Non-repetitive current pulse at $T_A = 25 \ ^{\circ}C$

Revision: 03-Dec-2018



10 V to 36 V

11.1 V to 44.2 V

3600 W

2800 W

5 W

500 A

175 °C

Uni-directional

DO-218AB

PRIMARY CHARACTERISTICS

V_{WM} V_{BR}

P_{PPM} (10 x 1000 µs)

P_{PPM} (10 x 10 000 µs)

 P_D

IFSM T_{.1} max

Polarity

Package

www.vishay.com

SM5S10A thru SM5S36A



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	R		MN				MAXIMUM	MAX. PEAK		
DEVICE TYPE	BREAKDOWN VOLTAGE V _{BR} (V)			STAND-OFF VOLTAGE V _{WM}	MAXIMUM REVERSE LEAKAGE	REVERSE LEAKAGE AT V _{WM}	PULSE CURRENT AT 10/1000 µs	MAXIMUM CLAMPING VOLTAGE	COEFFICIENT OF V _{BR} ⁽¹⁾	
	MIN.	NOM.	MAX.	(mA)	(M)	AT V _{WM} Ι _D (μΑ)	T _J = 175 °C I _D (μΑ)	WAVEFORM (A)	AT I _{PPM} V _C (V)	αT (%/°C)
SM5S10A	11.1	11.7	12.3	5.0	10.0	15	250	212	17.0	0.069
SM5S11A	12.2	12.9	13.5	5.0	11.0	10	150	198	18.2	0.072
SM5S12A	13.3	14.0	14.7	5.0	12.0	10	150	181	19.9	0.074
SM5S13A	14.4	15.2	15.9	5.0	13.0	10	150	167	21.5	0.076
SM5S14A	15.6	16.4	17.2	5.0	14.0	10	150	155	23.2	0.078
SM5S15A	16.7	17.6	18.5	5.0	15.0	10	150	148	24.4	0.080
SM5S16A	17.8	18.8	19.7	5.0	16.0	10	150	138	26.0	0.081
SM5S17A	18.9	19.9	20.9	5.0	17.0	10	150	130	27.6	0.082
SM5S18A	20.0	21.1	22.1	5.0	18.0	10	150	123	29.2	0.083
SM5S20A	22.2	23.4	24.5	5.0	20.0	10	150	111	32.4	0.085
SM5S22A	24.4	25.7	26.9	5.0	22.0	10	150	101	35.5	0.086
SM5S24A	26.7	28.1	29.5	5.0	24.0	10	150	93	38.9	0.087
SM5S26A	28.9	30.4	31.9	5.0	26.0	10	150	86	42.1	0.088
SM5S28A	31.1	32.8	34.4	5.0	28.0	10	150	79	45.4	0.089
SM5S30A	33.3	35.1	36.8	5.0	30.0	10	150	74	48.4	0.090
SM5S33A	36.7	38.7	40.6	5.0	33.0	10	150	68	53.3	0.091
SM5S36A	40.0	42.1	44.2	5.0	36.0	10	150	62	58.1	0.091

Notes

For all types maximum V_F = 2.0 V at I_F = 100 A measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum

⁽¹⁾ To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at T_J = V_{BR} at 25 °C x (1 + α T x (T_J - 25))

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL VALUE		UNIT			
Typical thermal resistance, junction to case	$R_{ ext{ heta}JC}$	1.0	°C/W			

ORDERING INFORMATION (Example)							
PREFERRED P/N UNIT WEIGHT (g)		PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
SM5S10AHE3_A/I (1)	2.505	I	750	13" diameter plastic tape and reel, anode towards the sprocket hole			

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

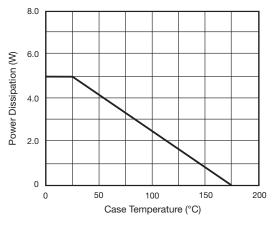


Fig. 1 - Power Derating Curve

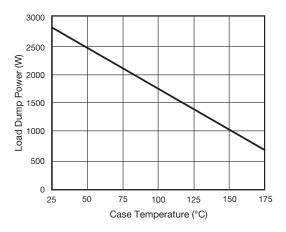


Fig. 2 - Load Dump Power Characteristics (10 ms Exponential Waveform)

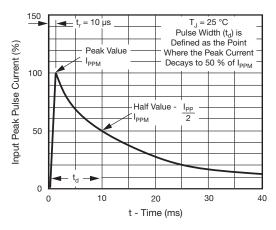
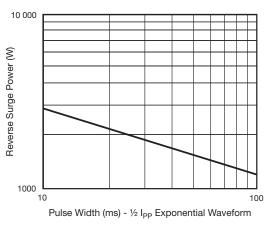


Fig. 3 - Pulse Waveform





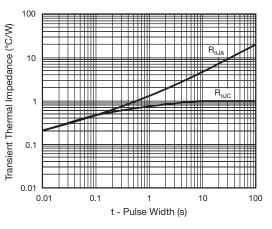


Fig. 5 - Typical Transient Thermal Impedance

Revision: 03-Dec-2018

Document Number: 88382

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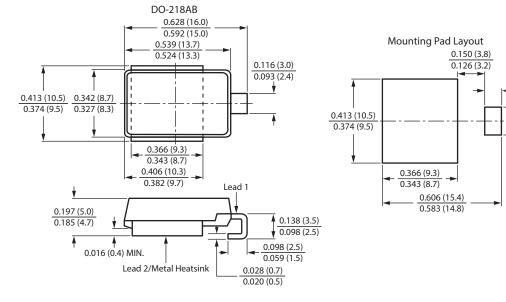
0.091 (2.3)

0.067 (1.7)

0.116 (3.0)

0.093 (2.4)

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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